

VEER SURENDRA SAI UNIVERSITY OF TECHNOLOGY (VSSUT), ODISHA
Mid Semester Examinations, Sept - 2024

COURSE NAME: B.Tech.
 BRANCH NAME: EL&TCE (Sec-A and B)

SEMESTER: 3rd
 SPECIALIZATION:

SUBJECT: ANALOG ELECTRONIC CIRCUITS

FULL MARKS: 30

TIME: 90 Minutes

Answer All Questions.

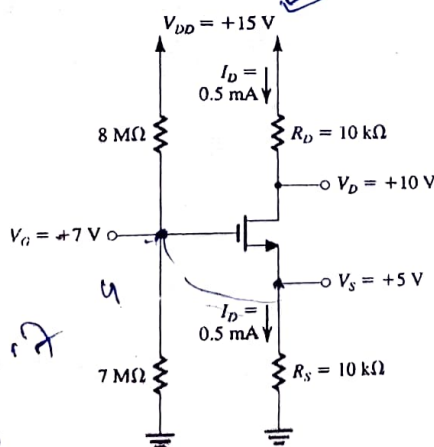
The figures in the right hand margin indicate Marks. Symbols carry usual meaning.

- Q1. Answer all Questions. Marks [2 × 3] COs
- Discuss the concept of load line and operating point of a BJT. Which is mostly used biasing circuit? Explain why it is mostly used. CO1
 - Draw and briefly explain the biasing of a MOSFET by fixing V_{GS} . CO2
 - Draw the frequency response a RC-coupled amplifier circuit and specify the different regions on it. Which components are responsible for low frequency and high frequency responses? CO3

- Q2. [8] CO1
- Draw and explain the difference between the emitter resistance bias and the emitter bias of a BJT.
- OR
- Explain the effect of R_S and R_L in small signal analysis of BJT amplifier circuit. CO1

- Q3. [8] CO1
- Define the model of a semiconductor device. Why a model is used? Draw the re model of a CE configuration and find the parameters, input impedance, output impedance, voltage gain, current gain. For a CB configuration with $I_E = 5\text{mA}$, $\alpha = 0.9$, $R_L = 0.5\text{K}$, and an ac signal of 6mV , determine the above-mentioned parameters and draw the re equivalent model for the transistor.
- OR
- Draw and explain the small signal equivalent model of common source amplifier with a source resistance R_S . CO2

- Q4. [8] CO3
- It is required to design a voltage divider circuit as shown in the figure given below to established a dc drain current $I_D = 0.5\text{mA}$. The MOSFET is specified to have $V_t = 1\text{V}$ and $k_n (W/L) = 1\text{mA/V}^2$. For simplicity, neglect the channel-length modulation effect (i.e., assume $\lambda = 0$). Use a power-supply $V_{DD} = 15\text{V}$. Calculate the percentage change in the value of I_D obtained when the MOSFET is replaced with another unit having the same $k_n (W/L)$ but $V_t = 1.5\text{V}$.



$$k_n (W/L)$$

$$I_D = k_n (V_{GS} - V_t)^2$$

$$0.5\text{mA} = k_n$$

OR

- Explain the concept of Miller effect capacitance. Find the input and output miller capacitances C_{Mi} and C_{Mo} . [8] CO3

(2.5)
 12.5
 1.1

$I_D = I_{C} = \beta I_B$
 $\beta = \frac{I_C}{I_B}$
 $\beta = \frac{I_{C1}}{I_{B1}} = \frac{I_{C2}}{I_{B2}}$